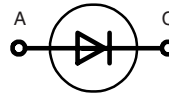


# HiPerFRED™ Epitaxial Diode

## with soft recovery

$I_{FAVM} = 8 \text{ A}$   
 $V_{RRM} = 300 \text{ V}$   
 $t_{rr} = 30 \text{ ns}$

$V_{RSM}$ V	$V_{RRM}$ V	Type	Marking on product
300	300	DSEP 8-03AS	8P030AS


**TO-252AA (DPAK)**


Symbol	Conditions	Maximum Ratings	
$I_{FRMS}$	$T_{VJ} = T_{VJM}$	20	A
$I_{FAVM}$ ①	$T_C = 152^\circ\text{C}$ ; rectangular, $d = 0.5$	8	A
$I_{FRM}$	$t_p < 10 \mu\text{s}$ ; rep. rating, pulse width limited by $T_{VJM}$	12	A
$I_{FSM}$	$T_{VJ} = 45^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine	60	A
$E_{AS}$	$T_{VJ} = 25^\circ\text{C}$ ; non-repetitive $I_{AS} = 2 \text{ A}$ ; $L = 180 \mu\text{H}$	0.5	mJ
$I_{AR}$	$V_A = 1.5 \cdot V_R$ typ.; $f = 10 \text{ kHz}$ ; repetitive	0.2	A
$T_{VJ}$		-40...+175	$^\circ\text{C}$
$T_{VJM}$		175	$^\circ\text{C}$
$T_{stg}$		-40...+150	$^\circ\text{C}$
$P_{tot}$	$T_C = 25^\circ\text{C}$	60	W
<b>Weight</b>	<b>typ.</b>	0.3	g

**Features**

- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low  $I_{RM}$ -values
- Soft recovery behaviour

**Applications**

- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

**Advantages**

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses
- Operating at lower temperature or space saving by reduced cooling

**Dimensions see Outlines.pdf**

Symbol	Conditions	Characteristic Values	
		typ.	max.
$I_R$	$V_R = V_{RRM}$ ; $T_{VJ} = 25^\circ\text{C}$	60	$\mu\text{A}$
	$V_R = V_{RRM}$ ; $T_{VJ} = 150^\circ\text{C}$	0.25	mA
$V_F$	$I_F = 8 \text{ A}$ ; $T_{VJ} = 150^\circ\text{C}$	1.13	V
	$T_{VJ} = 25^\circ\text{C}$	1.69	V
$R_{thJC}$		2.5	K/W
$t_{rr}$	$I_F = 1 \text{ A}$ ; $-di/dt = 50 \text{ A}/\mu\text{s}$ ; $V_R = 30 \text{ V}$ ; $T_{VJ} = 25^\circ\text{C}$	30	ns
$I_{RM}$	$V_R = 100 \text{ V}$ ; $I_F = 12 \text{ A}$ ; $-di_F/dt = 100 \text{ A}/\mu\text{s}$ $T_{VJ} = 100^\circ\text{C}$	2	2.4 A

①  $I_{FAVM}$  rating includes reverse blocking losses at  $T_{VJM}$ ,  $V_R = 0.6 V_{RRM}$ , duty cycle  $d = 0.5$

Data according to IEC 60747

**Recommended replacement:**  
**DPG10IM300UC**

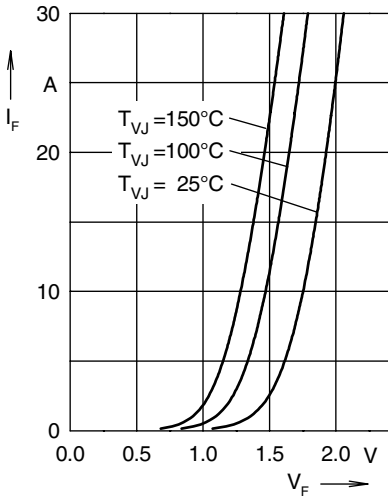


Fig. 1 Forward current  $I_F$  versus  $V_F$

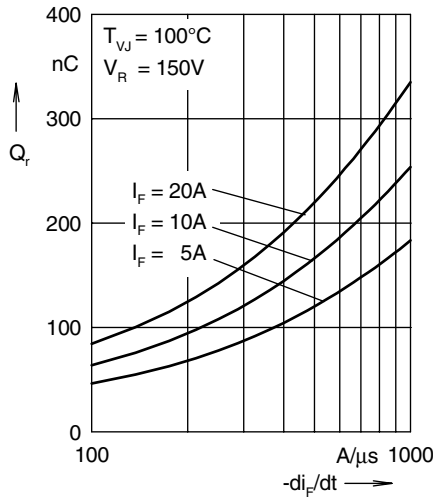


Fig. 2 Reverse recovery charge  $Q_r$  versus  $-di_F/dt$

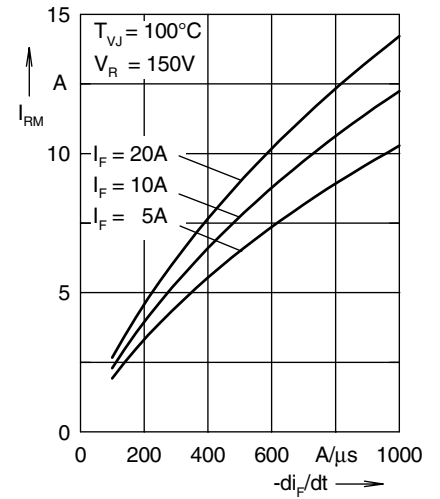


Fig. 3 Peak reverse current  $I_{RM}$  versus  $-di_F/dt$

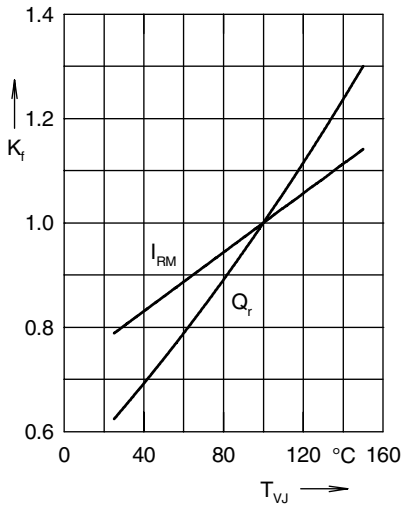


Fig. 4 Dynamic parameters  $Q_r$ ,  $I_{RM}$  versus  $T_{VJ}$

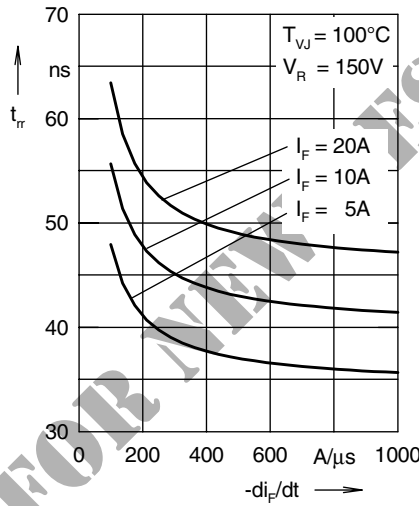


Fig. 5 Recovery time  $t_{rr}$  versus  $-di_F/dt$

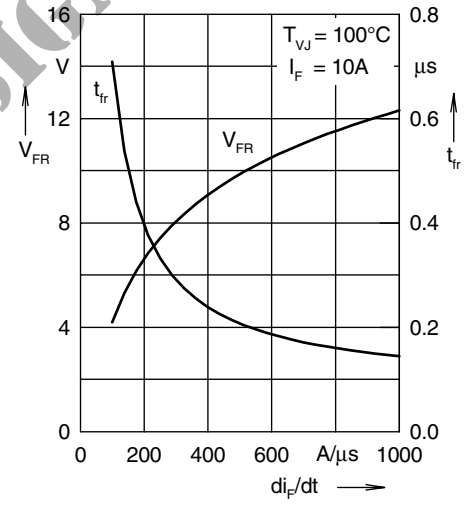


Fig. 6 Peak forward voltage  $V_{FR}$  and  $t_{fr}$  versus  $di_F/dt$

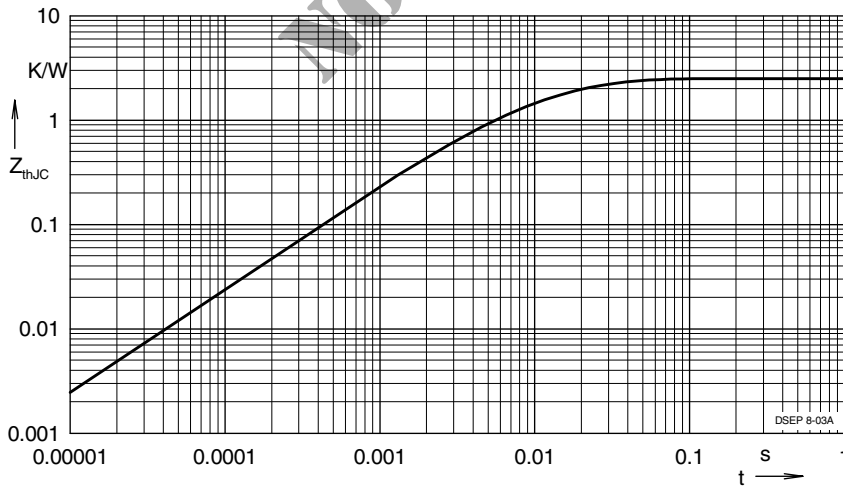


Fig. 7 Transient thermal resistance junction to case

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	1.449	0.005
2	0.558	0.0003
3	0.493	0.017